

ISPlasma/IC-PLANTS is specialized international symposium where about 1,000 world-leading scientists and engineers can get together in the Tokai region (central Japan) to discuss latest researches in the fields of advanced plasma science, its application for processing and manufacturing of wide-bandgap materials and nanomaterials. This symposium will address issues such as global warming, resources and energy problems to which advanced plasma science and its application technologies can greatly contribute. We aim that holding of this symposium stimulates progress of plasma science and its application, and contributes to the improvement of social life.

Related Fields

Plasma Science

- Plasma Source • Modeling and Simulation
- Thin Film Deposition Process • Etching Process
- Atmospheric-pressure plasma • Solution Plasma
- Advanced Plasma Measuring Technology • Plasma for Clean Energy
- Plasma Biology and Medicine • Plasma for Nanotechnology

Functional Semiconductors

- Crystal Growth of GaN and Related Materials • SiC/Diamond
- Optical Devices • MBE Growth of Nitrides • Power device
- Electron Devices

Nanomaterials and Micro fabrication

- Nano structured material • Catalyst/Battery • Solar Cell
- Environmental materials • Micro-TAS

Surface Functionalization

- Hard coating • Thin Films by chemical process
- Biosurface and biointerface • Functional thin films

JJAP Special Issue

Selected papers will be published in a Special Issue of Jpn. J. Appl. Phys. (JJAP).

Submission Deadline : April 17, 2015

Schedule at a glance

Mar. 26 (THU)	<ul style="list-style-type: none"> • Registration • Factory Tour • Welcom Party at Nagoya University
Mar. 27 (FRI)	<ul style="list-style-type: none"> • Openning • Plenary Lecture • Technical Session • Poster Session
Mar. 28 (SAT)	<ul style="list-style-type: none"> • Plenary Lecture • Technical Session • Poster Session
Mar. 29 (SUN)	<ul style="list-style-type: none"> • Plenary Lecture • Technical Session • Special Lecture from Nobel Laureate in Physics Nagoya University Prof. Hiroshi Amano • Banquet at Port of Nagoya Public Aquarium
Mar. 30 (MON)	<ul style="list-style-type: none"> • Plenary Lecture • Technical Session • Poster Session • Award • Closing • Excursion
Mar. 31 (TUE)	<ul style="list-style-type: none"> • Excursion

Registration

Please register on our website.

Advanced Online Registration is required.

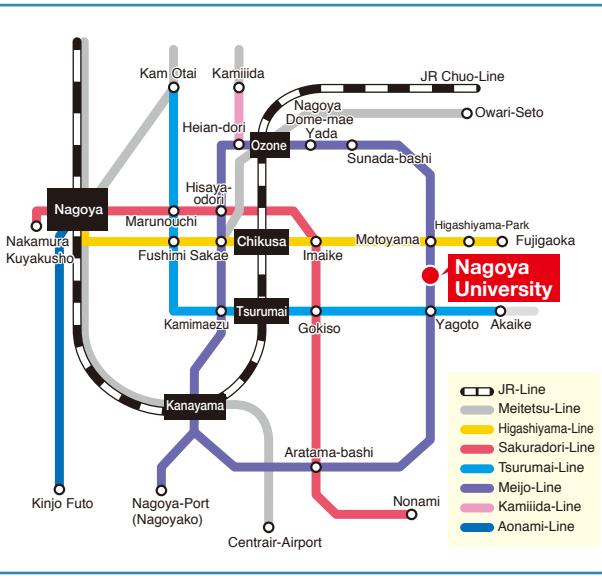
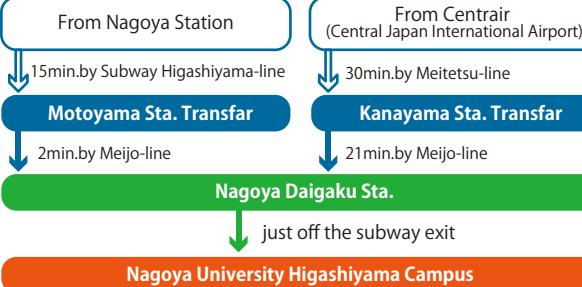
Registration Fee:	General	Student
Early Registration (Before Feb 28, 2015)	JPY 45,000	JPY 15,000
On-site Registration	JPY 50,000	JPY 20,000

Banquet Fee (On March 29, 2015)	JPY 10,000	JPY 10,000
(at Port of Nagoya Public Aquarium)		

* Refunds cannot be made at any reason.

Venue

Nagoya University | Furou-cho, Chikusa-ku, Nagoyashi, Nagoya JAPAN
TEL:+81-(0)52-789-5111(For General Information)



<http://www.isplasma.jp/>

ISPlasma2015 IC-PLANTS2015

March 26-31, 2015
Nagoya University, Japan



7th International Symposium on
Advanced Plasma Science and its Applications for Nitrides and Nanomaterials/
8th International Conference on Plasma-Nano Technology & Science

Organizing Committee

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Nagahiro Saito, Nagoya University

Vice-Chairperson

Keiji Nakamura, Chubu University

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ISPlasma2015 / IC-PLANTS2015 Organizing Committee

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Fusion Research, The Japanese Association for Crystal Growth

Contact

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ISPlasma2015 / IC-PLANTS2015 Program

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3/26(Th.)	3/27(Fri.)		3/28(Sat.)					3/29(Sun.)					3/30(Mon.)				3/31(Tue.)		
Excursion	Registration		Registration					Registration					Registration				Excursion		
			A6	B1	C1	C4	D1	A4	A6	B2	C3	C4	D4	A2	C5	C4	D4		
	Opening Address Nagoya Univ. Prof. Nagahiro Saito		Break					Break					Break						
	Plenary Lecture University of Houston, USA Prof. Vincent M. Donnelly (Plasma Science)		Plenary Lecture The University of Tokyo Prof. Kazunari Domen (Nanomaterials and Nano/Micro Fabrication)					Plenary Lecture The University of Tokyo Prof. Yasuhiko Arakawa (Functional Semiconductors)					Poster Session (A2, A5, A6, C3, C4, C5, D2, D4)						
	Plenary Lecture Kyoto University, Japan Emeritus prof. Hiroyuki Matsunami (Functional Semiconductors)		Plenary Lecture Linköping University, Sweden Prof. Ulf Helmersson (Surface Functionalization)					Plenary Lecture NTT Basic Research Laboratories, Japan G.R. Dr. Koji Sumitomo (Surface Functionalization)					Lunch						
	Registration		Lunch					Lunch					Plenary Lecture University of Surrey Prof. Ravi Silva (Nanomaterials and Nano/Micro Fabrication)						
	A1	B3	C1	C2	D3	A4	B1	C1	C4	D1	Break					Plenary Lecture Kyushu University Masaharu Shiratani (Plasma Science)		Excursion	
	A4	Poster Session (A1, B3, C1, C2, D3)					Poster Session (A3, A4, B1, B2, C1, C4, D1)					Special Lecture from Nobel Laureate in Physics Nagoya University Prof. Hiroshi Amano							
	Break					A5 A6 B2 C3 C4 D2					Award					Closing			
	Banquet (Port of Nagoya Public Aquarium)					Excursion					Excursion								
Welcome Party																			

Special Speakers

Prof. Hiroshi AMANO
(Nagoya University)
(Nobel Laureate in Physics)

March 29, 2015

14:00 - 15:20

Toyoda Auditorium, Nagoya University



Plenary Speakers

Prof. Yasuhiko ARAKAWA (The University of Tokyo, Japan)
Prof. Kazunari DOMEN (The University of Tokyo, Japan)
Prof. Vincent M. DONNELLY (University of Houston, USA)
Prof. Ulf HELMERSSON (Linköping University, Sweden)
Prof. Hiroyuki MATSUNAMI (Kyoto University, Japan)
Prof. Masaharu SHIRATANI (Kyushu University, Japan)
Prof. Ravi SILVA (University of Surrey, United Kingdom)
Dr. Koji SUMITOMO (NTT Basic Research Laboratories, Japan)

Sessions

Plasma Science

- A1 Plasma Engineering
- A2 Plasma Deposition
- A3 Plasma Medicine
- A4 Plasma Applications
- A5 Atmospheric Pressure Plasma
- A6 Solution Plasma

Functional Semiconductors

- B1 Nitride Process
- B2 Application of Nitride Semiconductors
- B3 SiC·Diamond·Other Related Materials

Nanomaterials and Nano/Micro Fabrication

- C1 Nanostructured and Nanocomposite Materials
- C2 Catalyst / Battery
- C3 Solar Cell
- C4 Environmental and Energy Materials
- C5 Microfluidics, Nanofluidics, and microTAS

Surface Functionalization

- D1 Hard Coating
- D2 Wet Coating
- D3 Functional Thin Films
- D4 Biosurface